NSN 5962-01-313-9920

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View Online at https://aerobasegroup.com/nsn/5962-01-313-9920

O III 4
Overall Length:
1.280 inches
Overall Height:
0.400 inches
Overall Width:
0.320 inches
Body Length:
1.280 inches
Body Width:
0.310 inches
Body Height:
0.185 inches
Maximum Power Dissipation Rating:
660.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Burn in and electrostatic sensitive and programmable and radiation hardened
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
15 input
Criticality Code Justification:
Feat
Case Outline Source And Designator:
D-9 mil-m-38510
Terminal Surface Treatment:
Terminal Surface Treatment: Solder
Solder
Solder Voltage Rating And Type Per Characteristic:
Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source
Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source Memory Device Type:
Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source Memory Device Type: Prom
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96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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Terminal Type Ar	nd Quantity:
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24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0